Flexible quintuple cation perovskite solar cells with high efficiency

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Fig. S1. SEM and XRD of RbCsFAMA films with different Rb⁺ cation additions.



Fig. S2. SEM and XRD of KCsFAMA films with different K⁺ cation additions.



Fig. S3. Cross-section SEM images of different perovskite films: a) CsFAMA (Control), b) Rb₅CsFAMA, c-f) Rb_{5-x}K_xCsFAMA (x varies from 1 to 4), and g) K₅CsFAMA



Fig. S4. The mean grain size and grain number of different perovskite films in Fig. 2.



Fig. S5. The J–V curves of the champion device based on $Rb_1K_4CsFAMA$ perovskite measured under backward-scan and forward-scan direction



Fig. S6. Long-term stability parameters of devices with different perovskite recipes without encapsulation, under controlled ambient conditions at approximately 10% relative

humidity.



Fig. S7. Time-resolved photoluminescence (TRPL) decay of the perovskites films, Rb_{5-x} $K_xCsFAMA$ (x=1-4) on bare glasses.



Fig. S8. AFM images of the SnO₂ layers on (a) ITO surface and (b) ITO/HfO₂ surface, respectively.



Fig. S9. XRD pattern of the $Rb_1K_4CsFAMA$ perovskite layer on top of ITO/HfO₂/SnO₂.



Fig. S10. Surface morphology of (a) the perovskite film on PEN/ITO/HfO₂/SnO₂ and (b) the perovskite film on Glass/FTO/SnO₂. (c) shows the distribution of their grain sizes and (d) shows the infrared thermographs of different substrates using an infrared thermometer (FLIR TG165) (The surface temperatures of the hot plate and the two substrates are 110 °C and 61°C, respectively)

It can be seen from Fig. S10. that the morphology of the perovskite on the flexible substrate and the rigid substrate barely change. Previous study showed that the roughness of the underlayer of perovskite has no effect on the perovskite layer.¹ The heating condition is one of the key factors affecting the perovskite film crystallization.² Considering the different thermal properties of flexible substrates and the rigid substrates, we compared the two substrates on hot plate as shown in Fig. S10(d). It can be seen that there is no obvious difference between the two heated substrates. Hence, the perovskite morphologies shown in Fig. S10 (a) and Fig. S10 (b) are almost the same.



Fig. S11. (a) Normalized PCE of the Rb₁K₄CsFAMA-based flexible device as a function of bending cycles with a curvature radius of 10 mm; (b) The graph of our home-made bending machine and (c) The initial IV curve of the tested device.



Fig. S12. PCE decay of devices kept at controlled ambient conditions at approximately 10% relative humidity; and kept at 85 in a N₂ environment in dark (To avoid the degration of Spiro-oMeTAD at 85 ° C, 10 wt% of CuPc was added to the hole transport film). Values are the averages for six devices.



Fig. S13. Nyquist plots of the flexible PSCs with/without HfO_2 layer.

| Samples (15 average) | Voc (V) | Jsc (mA cm ⁻²) | FF (%) | PCE (%) | Hysteresis index (%) |
|---------------------------------------|-----------------|-------------------------------|------------|------------------|-------------------------|
| CsFAMA | 1.09±0.01 | 21.65±0.26 | 77.38±1.34 | 18.32±0.49 | 13.28±3.49 |
| Rb ₅ CsFAMA | 1.11 ± 0.01 | 21.25±0.28 | 79.25±1.34 | 18.68 ± 0.50 | 11.14±3.15 |
| Rb ₄ K ₁ CsFAMA | 1.12 ± 0.01 | 21.51±0.25 | 79.30±1.38 | 19.03±0.24 | 3.62±1.71 |
| Rb ₃ K ₂ CsFAMA | 1.13 ± 0.01 | 21.84±0.10 | 79.07±0.72 | 19.46±0.24 | 2.15±0.75 |
| Rb ₂ K ₃ CsFAMA | 1.13 ± 0.00 | 21.96±0.17 | 79.39±0.58 | 19.75±0.17 | 1.85±0.79 |
| Rb ₁ K ₄ CsFAMA | 1.14 ± 0.01 | 22.20±0.16 | 79.21±0.30 | 20.13±0.15 | 0.89±0.36 |
| K ₅ CsFAMA | 1.12±0.01 | 21.86±0.16 | 78.35±0.65 | 19.15±0.24 | 3.12±1.23 |

Table S1. The photovoltaic parameters of the rigid PSC devices containing different monovalent cations.

Table S2. Lifetimes of different perovskites on bare glasses based on photoluminescence decay data. The data were fitted to exponential decay $(y=y_0+A_1exp[-(x-x_0)/\tau])$.

| Samples | τ (ns) | | |
|---------------------------------------|--------|--|--|
| CsFAMA | 27.98 | | |
| Rb ₅ CsFAMA | 38.01 | | |
| Rb ₄ K ₁ CsFAMA | 86.52 | | |
| Rb ₃ K ₂ CsFAMA | 128.71 | | |
| Rb ₂ K ₃ CsFAMA | 215.97 | | |
| Rb ₁ K ₄ CsFAMA | 333.25 | | |
| K ₅ CsFAMA | 180.48 | | |

Table S3. The photovoltaic parameters of the flexible PSC devices containing with different HfO₂ layers from different ALD cycles.

| Samples (10 average) | Voc (V) | Jsc (mA/cm ²) | FF (%) | PCE (%) |
|-------------------------|-----------------|---------------------------|------------------|------------------|
| Control | 1.11±0.01 | 20.17±0.08 | 77.62±0.86 | 17.43±0.15 |
| 2 cycles | 1.13 ± 0.01 | 20.85±0.11 | 77.66±0.79 | 18.29 ± 0.15 |
| 5 cycles | 1.13 ± 0.01 | 21.07±0.17 | 78.21±0.72 | 18.68 ± 0.26 |
| 8 cycles | 1.10 ± 0.01 | 20.29±0.13 | 79.52±1.06 | 17.80 ± 0.25 |
| 11 cycles | 1.07 ± 0.01 | 19.93 ± 0.09 | 78.84 ± 0.92 | 16.89 ± 0.31 |

References

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